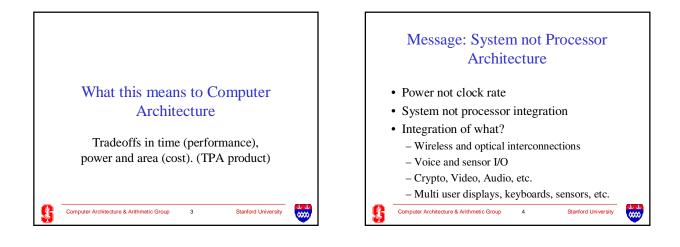
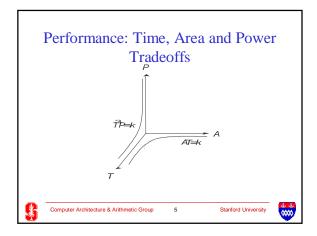
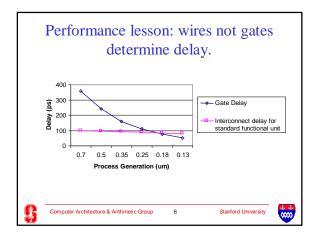
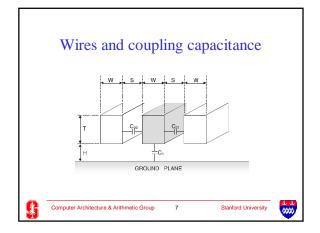


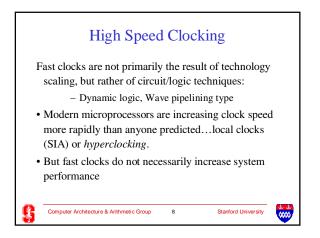
	Semiconductor Industry Roadmap						
Semiconductor Technology Roadmap (2001)							
Year	2001	2004	2007	2013			
Technology generation (nm)	130	90	65	32			
Wafer size (mm)	300	300	300	450			
Defect density (per m ²)	1356	1356	1356	1116			
μP die size (mm ²)	310	310	310	310			
Chip Frequency (MHz)	1767	4000	6700	19350			
MTx per Chip (Microprocessor)	276	552	1204	4424			
MaxPwr(W) High Performance	130	160	190	251			
Computer Architecture & Arithmetic Group	2		Stanford University				

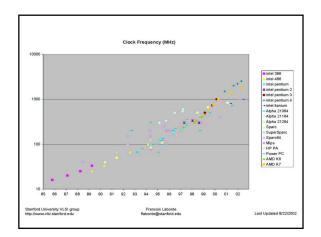


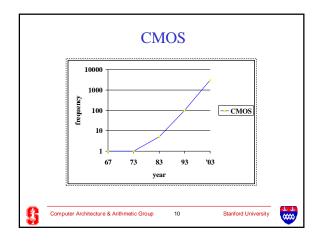


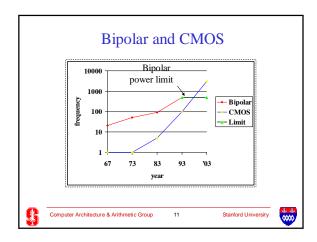


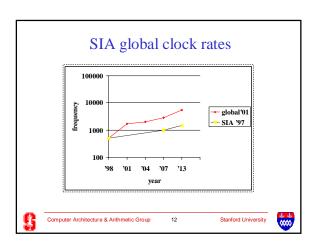


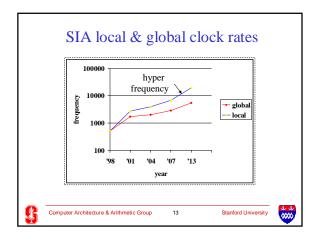


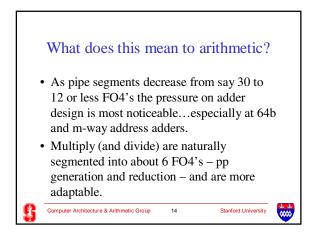


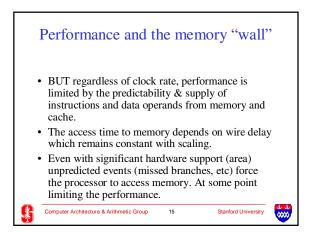


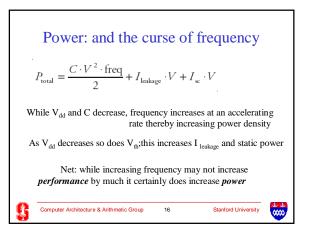


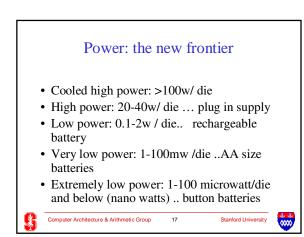




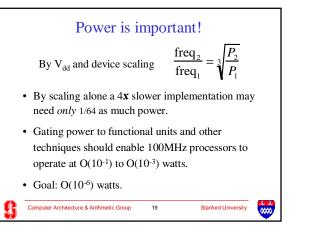


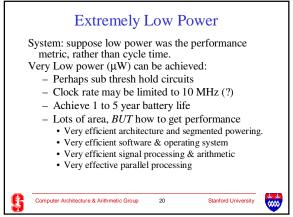


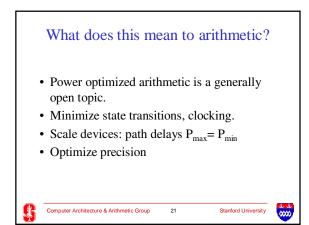


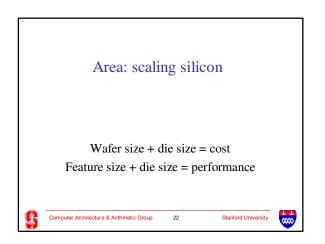


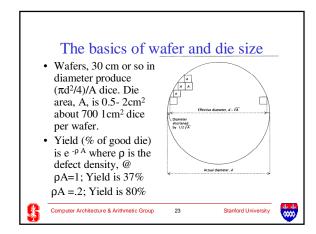
type	energy	time	power
	capacity		
recharage able	10,000 mAh	50 hours (10-20% duty)	400mw- 4w
2xAA	4000 mAh	¹ ⁄ ₂ year (10- 20% duty)	1-10 mw
button	40mAh	5 years (always on)	1uw

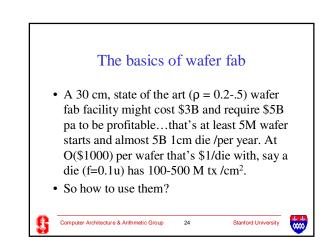


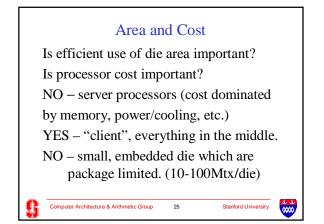


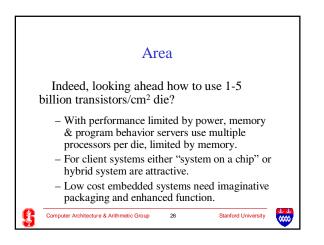


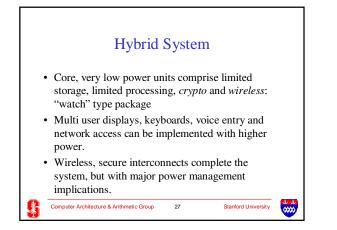














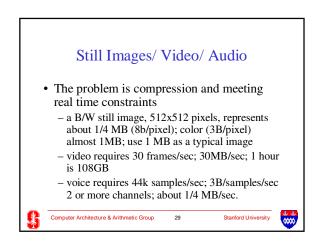
- Includes video, audio, 3 D graphic imaging, as well as subsidiary functions such as music (composition and rendering), voice recognition, handwriting rec., animation
- Closely coupled to the display / presentation technology (raster line or pixel density, audio speaker fidelity / range)

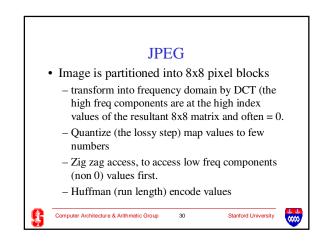
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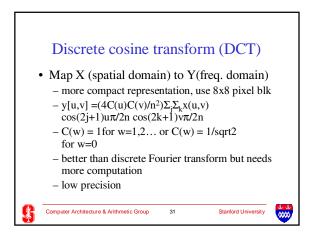
Stanford University

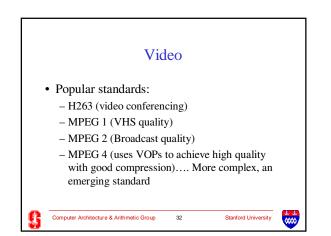
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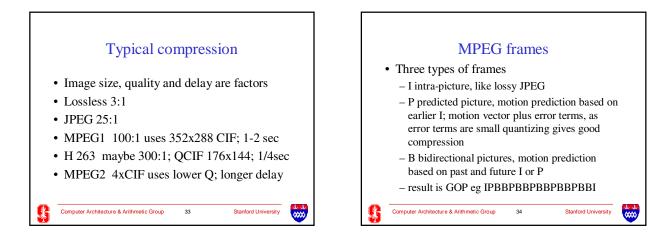
Computer Architecture & Arithmetic Group

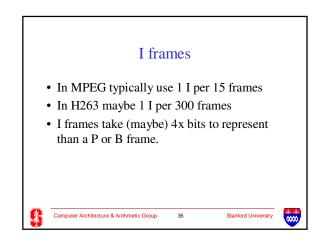


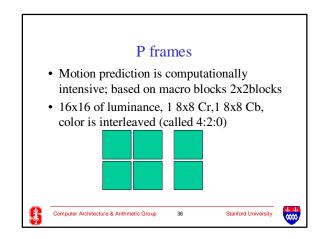


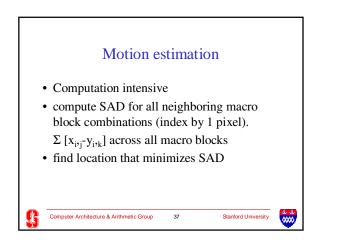


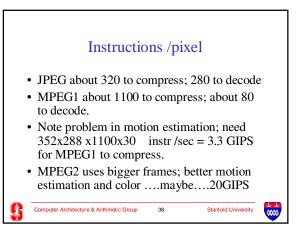


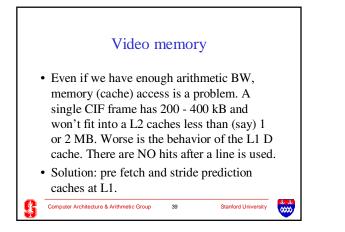


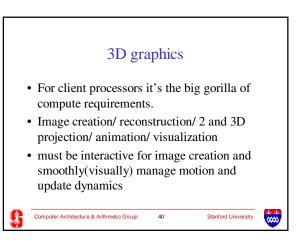


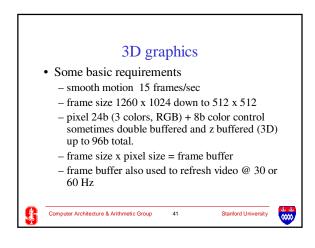


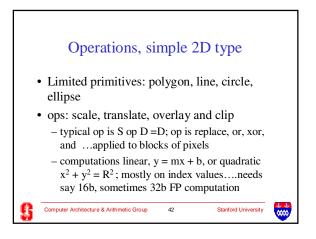


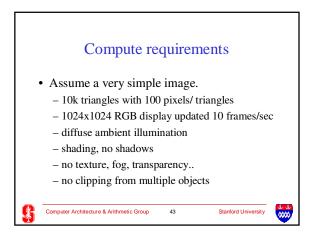


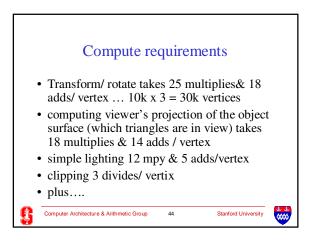


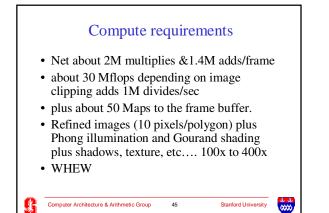




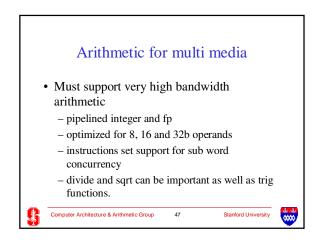


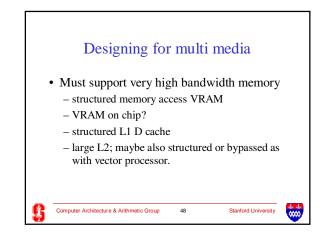


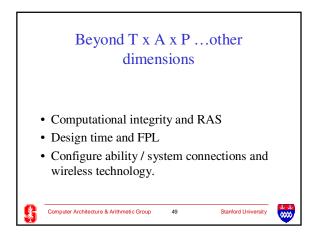


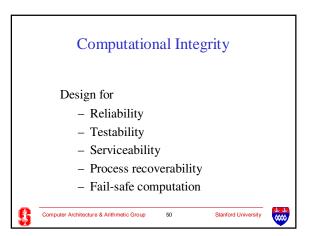


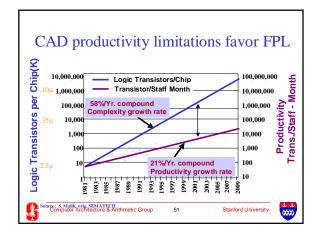


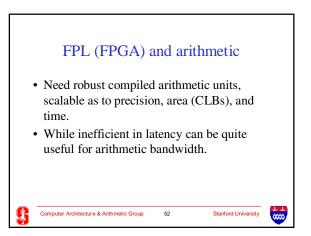


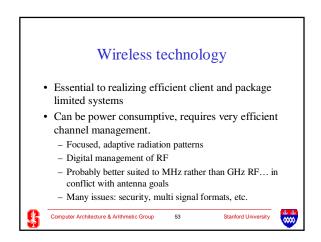


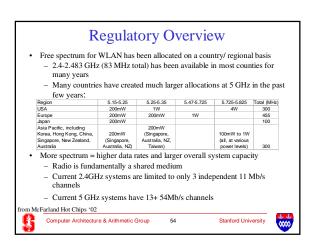


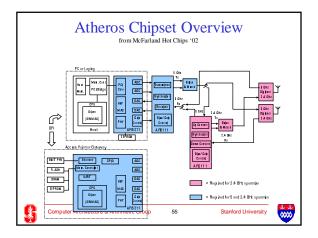


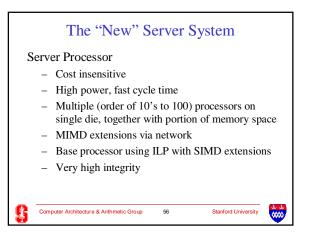


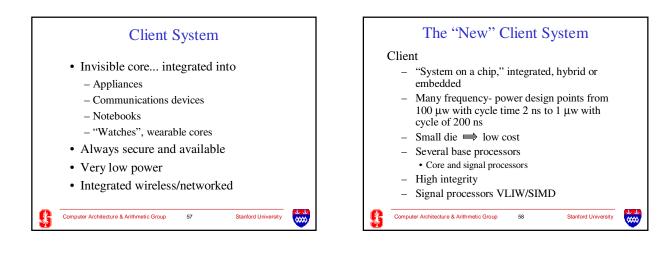


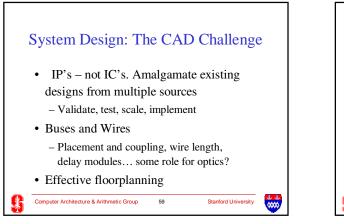














Summary

- Processor design with deep sub-micron (f < 90nm) technology offers major advantages: 10x speed or 10⁻⁶ power and 100x circuit density. Indeed, SIA projections have consistently underestimated the future.
- But the real challenge is in system not processor design: new system products and concepts, ip management and design tools.

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